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1. 1.5 kW PA MODULE 40D1493G1 or G2:

Drawing references: 40D1493, 30C1307, 40D1474, 30C1306, 40D1472, 20B1594, 30C1418 (Figs 3 thru 8).

The 1.5 kW module consists of a frame, a front panel, two heatsinks, a 6-way power splitter, six 250 W FET amplifiers, a 6-way power combiner, a VSWR protection board, and power & I/O connectors. It is designed for 1.5 kW sync peak power output in Low Band 54 - 88 MHz NTSC television systems, and provides power gain of approximately 20 dB, with 1.5 kW peak sync visual or 900 W aural output. It is fully plug-in, incorporating protective circuitry for "excess VSWR" power cutback and to allow "hot plug-in" while the transmitter is operational.

Some statements made in this document are applicable to modules working in parallel in higher powered transmitters, so are less significant when referring to single modules, such as used in the TTS1000B.

2. 6-Way Splitter/Input Board 40D1474G1 or G2:

References: 40D1474 & 30C1307. These are Figures 5 and 4 respectively.

The 6-Way power splitter receives its RF input signal as either the output from the IPA in the TTS1000B, or from one of the six outputs from the Visual Driver module in larger transmitters, and provides six input signals to integral input matching networks for the six FET amplifiers. The incoming signal is first split in three by a 3-way Wilkinson splitter, and the three resultant signals are split again by three 2-way Wilkinson splitters to provide the six outputs required. Terminations for the 3-way splitter are provided by R109, R110, and R111, with reactive trimming by L109, L110, and L111; and for the two-way splitters, terminations are R101, R103 and R105, with reactive trimming by C106, C116, and C126. Impedance match is provided by C145, C142, C138, C144, C145, C139, and C140 which make the path from the 50 Ω input to the six quarter- wave matching sections, into a low-pass π network. A built-in peak detector (CR102 and C147) is fed from a directional coupler on the input transmission line, to provide a sample of the input signal for module gain monitoring. R117 and R118 terminate the directional coupler, C148 provides an input match from the input connector to the input transmission line, and C149 is an RF bypass around the panel LED.

Observe that each pair of the six amplifier inputs are each given a phase quadrature with a combination of π and T networks that provide 45° lag and 45° lead respectively. Typical at amplifier #1 are C101, C103 which form a π network with the series inductance of a board trace, delaying the signal 45° to amplifier #1, and at amplifier #2 are C107, C108 combined with the shunt inductance of another board trace, causing the signal to lead by 45° at amplifier #2. The two are therefore driven in quadrature, with #2 leading #1 by 90°. Phase relationship is restored after amplification, by similar components on the output circuit board.

3. <u>Individual RF Amplifiers:</u>

References: 40D1474, 30C1307, 30C1306 sh 1, and 40D1472. Figures 5, 4, 6, and 7, respectively.

Each of the six amplifiers in the module consists of two, source grounded N-channel, insulated gate Field Effect Transistors (FETs) packaged in a single case, operating class AB in a push-pull configuration. Because these FET's are "enhancement mode" devices, they require positive gate-to-source bias voltage on each gate to cause source-drain conduction. The quiescent Class AB idling bias current is set at 0.5 ampere for each half. The gate voltage required to produce this idling current may vary between 2 V and 5 V according to the device specification sheet, and typically is 3 to 4 V. FET gate threshold voltages also are temperature sensitive, so thermal compensation is provided by R9, RT1, and R10, RT2.

Gate bias is supplied out of an adjustable voltage divider from the +39 V regulated bias rail. Resistors R1, R2, R3, R4 provide gate bias for one half of the amplifier, R5, R6, R7, R8 provide bias for the other half.

The RF input signal is applied to balun T1 to provide two signals 180° out-of-phase. These signals are stepped down to match the low input impedance of the FET device through a π -network consisting of C1, C2, C3, L1, L2, C4, and the device $C_{\text{G-S}}$, and then applied to the gates. The capacitance values of C3 and C4 are changed to configure the system for operation on channels 5 & 6. The gate input impedance at the operating frequency is low compared with the values of R3 and R6, which have little or no effect at RF.

R3 and R6 provide a DC path for bias, and provide loading at lower frequencies where gate impedance is high, in order to assist in maintaining amplifier stability. The choice of C6 and C7 values, and the series inductance of board traces, also ensures effective bypassing at critical frequencies of interest.

The output matching π -network, consisting of inductors L3 thru L8, and capacitances C13 thru C16, transforms the very low output impedance of the FET, upwards to a standard 50 Ω . The two antiphase output signals are finally combined in balun T2, L9. Jumpers placed across parts of L7 and L8, plus the changed values of C13, C14, C15 and C16, configures the system for channels 5 & 6 operation.

DC is applied to the FET drains through L3, L4 for the Q1A half, and L5, L6 for the Q1B half. L3 and L6 are short sections of microstrip line which transform the apparent RF impedances of L4 and L5 to higher values as seen by the FET. RF and lower frequencies are bypassed with paralleled C5, C9, C10 for one half of the amplifier, and C8, C11, C12 for the other half. These groups of capacitors are selected in value and for their internal equivalent series inductances so that they will be an effective bypass at critical frequencies of interest, including video, to assist in maintaining stability.

4. 6-Way Combiner/Output Board 40D1472G1 or G2:

References: 40D1472 & 30C1307. These are Figures 7 and 4 respectively.

The six amplifier outputs are applied to three 2-way Wilkinson combiners after each pair of these outputs are passed through T and π (lead and lag, respectively) networks to correct the quadrature condition imposed by the input splitter board. Typically, the T network is C102, C104, and the shunt inductance of one board trace, while the π network consists of C109, C110, and the series inductance of another board trace. The three outputs of these Wilkinson combiners are again combined by a 3-way Wilkinson combiner into a single 50 ohm, 1.5 kW output. Terminations for the Wilkinson networks are similar to those provided on the Input board described above, and consist of R100, C105, R102, C115, R104, C125 for the 2-ways; and R106, L106, R107, L107, and R108, L108 for the 3-way combiner. An output matching π network is formed by C131 thru C134, C136, C137, and C141, along with the series inductance of the board trace.

There is one directional coupler and one bi-directional coupler located after the final matching π network, between it and the RF output connector.

The directional coupler feeds a BNC connector on the module front panel, and is used for output monitoring. The bi-directional coupler provides DC samples corresponding to both forward and reflected power to the VSWR protection board for monitoring module gain and VSWR protection. Terminations for these coupler line sections are provided by R113, R114, and R115; the RF samples for VSWR monitoring are peak-detected by CR100, C143, and R112 for "forward" and by CR101, C146, and R116 for "reflected".

VSWR Control Board 20B1594G1: Refs: 20B1594 & 30C1418 (Figure 6).

The VSWR control board does a number of things: it provides regulated bias voltages to the FET power amplifier stages, it provides hot-plug-in capability to protect the amplifier module when plugged into an operating transmitter (in transmitters using a number of modules in parallel), it provides protection to the FETs against over-dissipation due to high VSWR, and it monitors the module RF power gain.

If the module is plugged into a powered transmitter using several modules running in parallel, the power supply connections are first made through the long thin contacts of the DC power connector and into VSWR board J1 pin 8. This allows the video bypass capacitors of all amplifiers to charge through current limiting resistor R5, preventing overstress of all amplifier fuses due to charge current of the bypass capacitors. When the module is pushed home, the wide high current contacts are now connected and the module can operate normally.

VSWR Control Board 20B1594G1: Refs: 20B1594 & 30C1418 (Figure 6). (continued).

In normal operation the power supply enters J1 via pin 2, and is regulated to +39 VDC by series resistor R10 and zener diode VR1. Regulator U1 provides constant B+ voltage for op-amps U2, U3, U4, and the comparator reference voltages. When the module is first turned on (or plugged in) and U1 begins regulating, the charging current of C7 turns on Q1 which pulls the bias line low for a brief period of time. This provides a slow start for the module after DC power is applied.

The overall RF system achieves precise VSWR sensing from the external RF detector boards discussed in other sections of this manual, but VSWR sensing is also provided in the module for its own safety.

In the higher powered transmitters using modules in parallel, one or more dead or disconnected modules or a fault in the six-way combiner or subsequent 3 dB coupler, causes a module output mismatch.

To the module, any mismatch appears as reflected power which is detected and applied thru pin 11 of J1 to comparator circuit U2B.

R21 sets the level at which VSWR protection begins. If the level of detected reflected power on pin 5 of U2B exceeds the control voltage set on pin 6, the output on pin 7 will go high. R22, C10, and CR1 provide a fast attack, slow release control voltage to Q2 when a high VSWR condition suddenly occurs. This will turn on Q2 which turns on Q4 which quickly reduces the bias applied to the power amplifier FETs; this reduced bias also reduces their gain and therefore their RF output and keeps their heat dissipation at safe levels.

The next two paragraphs apply to modules used in parallel in higher powered transmitters:

"When a module is plugged into an operating transmitter, the slow start circuitry consisting of C7 and Q1 will initially keep the module turned off. Power from the other modules working into the combiner will enter the module and be detected by the reflected power detector. This would prevent the module from ever operating properly, unless the VSWR circuit is momentarily over-ridden.

The circuit of U4 produces a pulse approximately 2 seconds after power is applied to the module. At power-up, pin 2 of U4 will be pulled high by C11. R26 charges this capacitor, and when the pin 2 voltage goes below the voltage on pin 3, the output of U4 will go high. A pulse whose duration is controlled by C9 and R18 will then be applied to pin 3 of U2A. U3B detects that the module is not producing forward power and that the reverse power is high. Under these conditions the output of U2A goes high, turning on Q3, momentarily disabling VSWR protection, and allowing the module to come on."

DC samples corresponding to forward power into and out of the module are applied to U3A pins 2 and 3 respectively. When pin 3 voltage is higher than that of pin 2, corresponding to "RF gain is okay" the comparator output U3A pin 1 is high, causing the green LED on the front panel of the module to light. The comparison threshold (ie. module gain is ok) is set by adjustment of R4.

Unwanted RF pickup due to the proximity of the front panel LED to the module input on the input splitter board is minimized by C149 at the LED, bypassing any RF directly to ground. The low pass filter section consisting of L1 and C5 on the VSWR board effectively discourages or prevents stray RF from upsetting the operation of U3A.

6. Adjustment of bias voltage to establish proper quiescent FET bias current:

Important: 50 Ω input and output terminations are necessary to achieve consistent results when testing modules. Termination is relatively simple for the PA modules.

- Remove all fuses from the module to be tested. (There are 12 fuses in the 1.5 kW module).
- 2. Adjust all bias pots to maximum resistance, for minimum bias voltage. (Again, there are 12).
- 3. Use a clip lead to short the junction of C7, R6, R7 and R10 to ground. This shuts off side B of the amplifier so it will not interfere with measurement of bias current from side A.
- 4. Terminate the RF input and output into a 50 Ω load.
- 5. Apply +50 VDC from a lab power supply, through an ammeter, to the B+ copper bus, and its negative to chassis. **Caution:** Observe polarity! This power supply should have variable current limit protection such that the current can be limited to approximately 1 amp for the bias adjustment.
- 6. Check the voltage on the bias terminals, it should be 39 V ±2 V. (The bias terminals are connected together via insulated bus wire).
- 7. Read the current drawn by the VSWR board and bias regulator. Next, install a fuse in side A (nearest the panel) of amplifier #1; adjust the corresponding bias pot for a 800 mA increase in the power supply current; this increase corresponds to an idling bias current of 0.8 A. Remove the fuse. Remove the side B bias short and place it on side A at the junction of C6, R2, R3 and R9. Place the fuse in side B. Adjust the side B bias pot for 800 mA increase in power supply current.
- 8. Move the fuse to the remaining fuse holders, one at a time, and adjust each companion bias pot for a current of 800 mA.
- 9. Install remaining fuses and remove the bias short after all bias adjustments have been made.

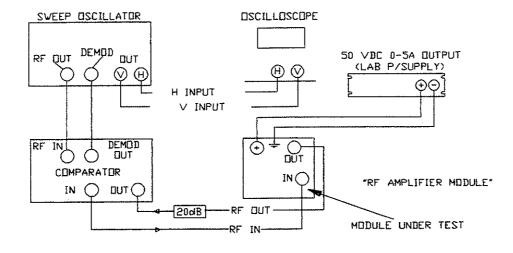
7. <u>Low power sweep of 1.5 kW Low Band amplifiers:</u>

- 1. Ensure that terminations are in place in the test setup. All modules require 50 Ω source and load impedances for consistent results during testing.
- 2. Connect the lab power supply +50 V to the copper B+ rail, and the negative to the chassis of the amplifier. The current should be limited to 12A for this test. **Caution:** observe polarity!
- 3. Connect the module to a sweep system, typically as shown in Figure 1. The sweep generator should be adjusted to give a linear sweep from about 45 to 75 MHz, or from 65 to 95 MHz, to sweep the part of Low Band that the module is intended for, with a small amount of out-of-band signal on both ends. Ensure that a coaxial 20 dB attenuator pad is connected to the RF output of the amplifier, in order to prevent possible damage to the sweep comparator.
- 4. With the power supply switched on, the current drawn should not be more than about 9.6 amperes (12 x 0.8 A) for the 1.5 kW module.

The swept in-band frequency response, for Low Band modules, should be essentially flat within ± 1 dB as shown in Figure 1, with gain approximately 21 ± 2 dB. (High Band modules have lower gain due to the RF device characteristics. Low Band sweep curves are usually > 20 dB gain.)

Ignore those parts of the response that are out-of-band; many modules will show harmless peaks and valleys that appear to be of significantly greater observed amplitude than the in-band swept response.

7. Low power sweep of 1.5 kW Low Band amplifiers: (continued).



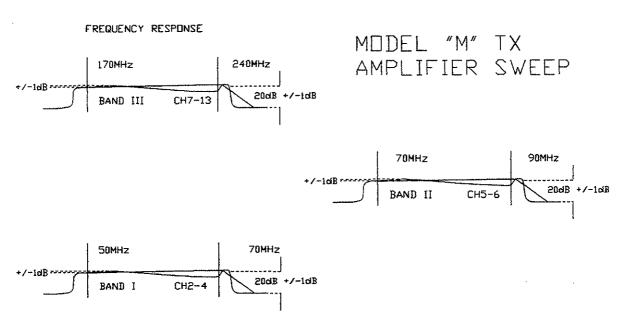


Figure 1: Module Sweep Set-up.

Out-of-band peaks and valleys are mostly due to the effects of the various reactances present in the circuit, including the "hidden" ones found in the FETs themselves, and should not affect overall performance.

It is only natural that most of us will want to try and improve anything and everything we are able in the transmitter, and module swept frequency response may be judged to be no exception. However, before you succumb to temptation, we must caution you that getting any wideband amplifier sweep response to look "right" is an endeavour not to be undertaken lightly. Adjusting sweep response is an exacting task and not a job that can be done easily or quickly. Even the replacement of an obviously damaged component may be cause for concern, because surface mounted chip capacitor positioning can be critical, and a fully equipped RF laboratory is the only environment in which such an undertaking would have a reasonable chance for success.

If you believe the sweep response is bad enough that you think you should fix it, the chances are good that one or more defective components are present in the module, and you therefore have choices: Rent or buy a lab setup of RF test equipment, or return the module to LARCAN for repair and realignment. Many of our customers have purchased extra modules for use as spares.

8. Factory Test Fixture and Module Adjustments:

In the LARCAN factory, the VSWR cutback and Green LED adjustments are carefully done with the PA module placed in a test fixture equipped with: a 500 cfm @ 1" SP cooling blower, a big DC power supply with adjustable output 0-60 V and current limit 0-90 A, two digital voltmeters, an ammeter shunt (50 mV at 50 amps) or a clampon DC current probe for one digital voltmeter, two in-line wattmeters and their sampling elements, a 1 kW dummy load, an adjustable gain (0-50W) RF driver amplifier, an exciter aural section or a signal generator (testing is done with CW), and suitable interconnecting cables.

Because the VSWR cutback and Green LED circuits have been adjusted at the factory, and are considered to be stable, they should not normally require any field adjustment. In fact, field adjustment is difficult because all the adjustment potentiometers are located on the BACK of the module; any adjustment is then impossible when the module is powered-up inside the transmitter. The Green LED adjustment, however, can be done incrementally with the module out of the transmitter, as follows:

9. Green LED Sensitivity Adjustment: (Incremental, on-site field method):

One of the functions of the VSWR board is to monitor the overall gain of the 1.5 kW module. This VSWR board is located at the rear of the module, adjacent to the output RF connector. For the locations of the components on the board, please refer to Drawing 20B1594 (Assembly diagram of Figure 8).

Verify that all the 1.5 kW modules are in good working order, and then proceed as follows:

- 1. With all modules running at normal operating power, place AGC/MANUAL switch into the MANUAL position and adjust the exciter output power until the transmitter output power reads 110%.
- 2. Remove the module to be set up, and remove the two front fuses from it, in order to simulate a single FET package failure. Replace this "crippled" module in the transmitter, and apply a 50% APL staircase video signal to the transmitter.
 - The green LED should now be extinguished; if it is not, remove the module and adjust the blue potentiometer (R4) on the VSWR board clockwise, replace the module and try again, repeating until the LED is barely extinguished when the module is re-powered. (Early boards used a pot whose rotation was opposite and required to be turned counterclockwise to turn off the LED).
- 3. Replace the fuses so the module is again fully operational, and verify that the green LED is now fully lighted when the module is replaced in the transmitter and re-powered.
 - It is recommended that R4 be adjusted one half turn at a time, to establish a known reference point.
- 4. Place the AGC/MANUAL switch in the AGC position, and with the RAISE/LOWER switch, readjust the transmitter output power to 100%.
- 5. Similarly, the aural amplifier in externally diplexed transmitters may be adjusted in the same manner, but obviously there is no requirement for a video input signal.

9. Green LED Sensitivity Adjustment: (continued).

Factory Adjustment of R4:

In the LARCAN factory test fixture, with an uncrippled good High Band module, the power supply voltage is simply lowered until the module output is reduced to 83% (5/6) of its initial power, and R4 is adjusted to barely extinguish the LED. This factory procedure depends on the fact that these FETs are constant current devices thus their gain is a linear function of the supply voltage.

For a Low Band module, there was a tendency for stray RF on our test fixture to obscure a correct adjustment, so our factory procedure is of necessity a little different. In this Low Band case, the setting of R4 starts at full clockwise with full power out of the module and the LED off, then R4 is advanced to barely turn on the LED and then adjusted ½ turn past that point. This method is considerably more dependent on the skill and experience of the test technician, but the result seems to work out to a similar gain reduction.

In any event, the incremental method described above, will work with any module.

Our final test technicians use the incremental method if they find the LED setting is incorrect during their final transmitter tests, but they depend on the fixture method of setting that is done during module test, to establish their R4 starting point.

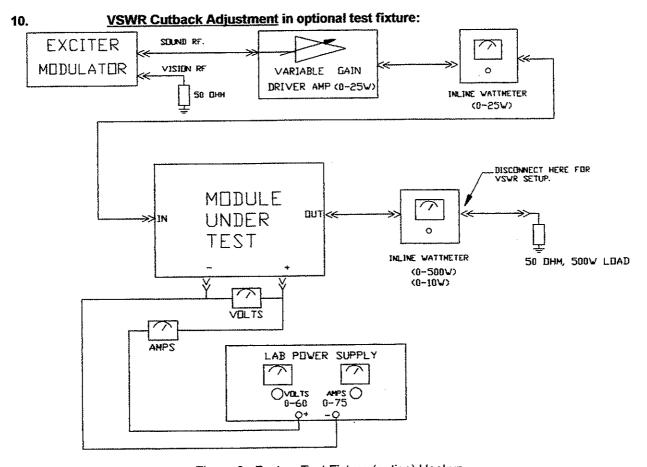


Figure 2: Factory Test Fixture (option) Hookup.

CAUTION: Adjustment of the VSWR cutback potentiometer R21 should only be attempted with the module in a properly configured test fixture, because it must be adjusted with RF drive, and at full power.

The VSWR board is located on the BACK of the module, and because the 6-way output combiner in higher powered transmitters is located behind the modules and is essential to the transmitter operation, it is impossible to reach R21 when the module is in the transmitter.

If a test fixture is unavailable, a better course of action is to return the module to LARCAN for adjustment.

Procedure:

When a test fixture is available, use the exciter aural section as a CW generator, make connections per Figure 2 (Page 8), and do this:

- 1. Start with everything (except the exciter) turned OFF, and with the driver RF gain and the power supply controls turned down to minimum.
- Place the module in the test fixture, start the blower, and ensure that air flows through the heatsink.
 Connect the input, output, and DC cables to the module. BE SURE THERE IS NO RF INPUT TO THE MODULE.
- Switch the power supply ON, advance the power supply current limit control to about 10 A, and watch
 the output in-line RF wattmeter with its most sensitive sampling element in place, while increasing the
 power supply voltage gradually to 50 V.
 - If RF is observed, STOP right there! RF indicates instability in the amplifier which must be investigated and corrected. A spectrum analyzer, if available, is a much more sensitive instrument for the detection of stray RF, but care must be taken that the input of the analyzer is protected from being damaged by too-high RF levels.
- 4. If RF was not observed during step 3, change the output in-line RF wattmeter sampling element to 1000 W full scale. Increase the power supply current limit to maximum, increase the voltage to 50 V, turn on the aural section of the exciter, and gradually advance the RF gain control of the driver amplifier until the module output RF reads 1000 W. This CW power level is a convenient amount that is chosen because RF wattmeters are most accurate at full scale, and it is only about 0.5 dB higher than the 893 W average power contained in a 1.5 kW sync peak visual signal at black level.
- 5. Observe the DC input voltage and current. Their product is the DC input power. The RF output power divided by the DC input power and multiplied by 100 is defined as the efficiency of the module. Typically at 1000 W output CW, the efficiency will be around 40%. Observe the RF input power. It should be about 10 to 12 watts. The module gain in dB is 10 times the logarithm of the ratio (Po/Pi) and is typically around 20 dB.
- 6. Reduce the RF gain to read 400 W at the module output. Adjust the power supply current control to begin limiting at this RF level. This avoids the possibility of damage to the FETs while subsequent adjustments of VSWR cutback are being made.
- 7. Reduce the RF gain to zero and disconnect the dummy load cable from the output RF wattmeter. This places an extreme output mismatch on the module. (The output RF wattmeter must remain connected to the module). Gradually increase the RF drive until the output wattmeter reads maximum, but avoid increasing input power to more than 30 W.

10. VSWR Cutback Adjustment in optional test fixture: (continued).

- 8. Adjust R21 until the output RF power decreases to 300 W. For the module, this represents an extremely high VSWR. Accuracy is not an issue; the objective here is simply to get an R21 cutback setting that will save the FETs from over-dissipation when high VSWR is seen by the module itself. (For the external RF system of the station, ie. the diplexer or filters, patch panels, line, and antenna, the output metering circuits of the transmitter respond accurately to pre-set VSWR).
- Adjust the RF input to the module, until the original input RF power of about 10 to 12 W is reached.
 Gradually increase the power supply current limit. The unterminated RF output from the module should not exceed 300 W under any circumstances.
- Shut off the RF drive, and re-terminate the module. Apply RF drive again, and increase the power supply current limit to maximum. The module operating conditions should be the same as in step 5; ie. output should be 1000 W, and the input drive between 10 and 12 W.
 - For a Low Band module, leave the supply alone and with the module putting out 1000 W, turn R4 clockwise enough that the green LED is off, then advance R4 counterclockwise to barely light the LED, and then turn it another ½ turn past that setting. (If desired, and if your test fixture is different than ours, try reduction of the power supply voltage and try adjusting R4 as described on page 7 for the High Band unit; perhaps it will work for your fixture. With our own test fixture, stray RF gave us no guarantees. This is why we also describe the incremental method in part 9, page 7).
- 11. Shut off the RF drive and the power supply. Disconnect the module, and reinstall it in the transmitter. Restore transmitter connections to the exciter if it was used to generate the CW signal for the RF driver amplifier in the fixture.

This completes the adjustments that are possible to be made on the module. Of course, if the test fixture is available, the sweep response can be measured, and bias settings can be done as well; the same basic technique applies, as described in Sections 6 and 7 above.

Cable lengths in the factory test setup are not considered to be critical; for your information, the LARCAN factory test fixture uses a straight reducing adapter (from module output to type N), followed by a right angle type N adapter between the module output reducer and the RF thruline wattmeter input. (There is no cable used; the total distance through the connector combination is about 10 cm from the module output to the wattmeter input). Approximately 60 cm of Teflon dielectric coax cable is then connected between the output connector of the wattmeter and the 1000 W dummy load.

Our test signal used for Low Band comes from a lab signal generator at about 65 MHz for the ch 2 - 4 split, and about 80 MHz for the ch 5 & 6 split. Of course, if your CW comes from the aural output of your exciter, then the frequency naturally will be on your operating channel, which is all that is really necessary.

In all fairness, we must state that although a test fixture can be built by station technicians, it will not be a cheap nor simple venture due to the requirement for a variable gain RF amplifier (adjustable over an 80 dB range - that's why we use a commercial signal generator) and for a high current adjustable power supply, both of which represent significant expenditures, especially for considerably more engineering time than many of us would care (or dare) to acknowledge.

Beginning on the next page, there are two parts list sets for the channels 2 thru 4 and channels 5 & 6 transmitters, respectively. To avoid on-site confusion, you may wish to remove and discard the set you don't need. Page numbering is the same for both parts list sets.

11. <u>1.5 kW Module Parts Lists</u>: Channels 2, 3, and 4:

Level	Parent No.	Description	Quantity
0	MODEL NO.	TRANSMITTER CH2-4	1 EA
1.	CABINET NO.	CABINET ASSEMBLY CH2-4	1 EA
2	HOUSING NO.	MODULE HOUSING ASSEMBLY CH2-4	1 EA
3	40D1493G1	1.5kw module asm ch2-4 R-9	l EA
Symbol		Description	Quantity
	40D1493P1	ASSEMBLY DRAWING	EA
	30C1192G6	FRONT PNL ASM 1.5KW PWR AMP R-6	1 EA
	10A1270G1	DC CONNECTOR ASM MALE R-3	1 EA
	10A1296G1	PCB ASM & RF CONNECTOR R-4	1 EA
	20B1594G1	PCB ASM VSWR CONTROL R-9	1 EA
	40D1472G1	PCB ASSY OUTPUT CH2-4 R-15	1 EA
	40D1474G1	PCB ASSY INPUT CH2-4 R-14	1 EA
	40D1467P1	FRONT HEATSINK MODIFIED R-16	1 EA
	40D1467P2	REAR HEATSINK MODIFIED R-15	1 EA
	20B1128P1	MODULE SUPPORT & SLIDE R-8	1 EA
	20B1128P2	MODULE SUPPORT & SLIDE R-8	1 EA
	BJ120	BULKHEAD JACK (INPUT)	1 EA
	10A1154P1	INPUT CONNECTOR MOUNTING PLATE R-2	1 EA
	8483 (ALUM)	SPACER #4 SCREW	2 EA
		DC CONNECTOR MOUNTING BLOCK R-4	1 EA
	10A1159P1	DC CONNECTOR MOUNTING BLOCK R-4	1 EA
	10A1159P2	COVER R-0	2 EA
	30C1458P1	COVER K-0	
	20B1600P1	HARNESS	1 EA
	CE100F24-11	END CONNECTOR	1 EA
	EC100F-11	COVER	1 EA
	10A1550P1	SPACER M/F #4/#4	4 EA
	20B1407P1	BUS BAR R-1	1 EA
	SRF3943-2	TRANSISTOR FET N-ch Dual	6 EA
	10A1564P1	TRANSISTOR CLAMP R-3	6 EA
	10A1566P1	PRESSURE PLATE CLAMP R-3	6 EA
	312007	FUSE 7A 250V <fast></fast>	12 EA

Level	Parent No.	Description	Quantity
. 3	40D1493G1	1.5KW MODULE ASM CH2-4 R-9	1 EA
4	30C1192G6	FRONT PNL ASM 1.5KW PWR AMP R-6	1 EA
Symbol	Part No.	Description	Quantity
	30C1192P6	ASSEMBLY DRAWING	EA
	40D1383P5	FRONT PANEL R-13	1 EA
	2-G	GUIDE stainless steel	2 EA
	2-L	LATCH stainless steel	2 EA
	2-R-113	RIVET	2 EA
	2-W	WASHER stainless steel	2 EA
	415-2111-020200	HANDLE	1 EA
	559-0201-001	LED GREEN	1 EA
	UG-625B/U	RECEPTACLE BNC sub 31-236	1 EA
		LARCAN INC. Parts List	
Level	Parent No.	Description	Quantity
3	40D1493G1	1.5KW MODULE ASM CH2-4 R-9	1 EA
4	10A1270G1	DC CONNECTOR ASM MALE R-3	1 EA
Symbol		Description	Quantity
	10A1270P1	DC CONNECTOR ASSEMBLY DWG	EA
	10A1177P1	GROUNDING BRACKET R-6	1 EA
	10A1269P1	LOCKING RAIL R-2	2 EA
	1410-14	TERMINAL LUG	1 EA
	EC-002	END CAPS	2 EA
	FP-2-04	PIN MODULE F	1 EA
	KP-000	CONNECTOR MODULAR	2 EA
		_	

LARCAN INC.
Parts List

Level	Parent No.	Description	Quantity
3	40D1493G1	1.5kw module asm cH2-4 R-9	1 EA
4	10A1296G1	PCB ASM & RF CONNECTOR R-4	1 EA
Symbol	Part No.	Description	Quantity
_	10A1296Pl	ASSEMBLY DRAWING	EA
-	10A1298P1	CONNECTOR KEY	EA
	10A1295P1	PCB RF CONNECTOR R-5	1 EA
_	10A1399P1	PCB INSULATOR BOARD R-3	1 EA
	20B1332G1	CONNECTOR ASM purchase complete R-2	1 EA
_	663-110	SOLDER LUG ZIERICK	1 EA
***	B1570-B-3/32-12	SPACER	1 EA
-	HN-9B	NUT BRASS 1/4" A/F	1 EA

Level	Parent No.	Description	Quantity
3	40D1493G1	1.5KW MODULE ASM CH2-4 R-9	1 EA
4	20B1594G1	PCB ASM VSWR CONTROL R-9	1 EA
	Part No.	Description	Quantity
-	20B1594	ASM/PATTERN/SILKSCRN/SOLDMSK	EA
-	30C1418	SCHEMATIC R-6	EA
an-	20B1594P1	PCB VSWR CONTROL R-2	1 EA
	508-AG11D	IC SOCKET 8 PIN	3 EA
	B1570-B-1/4-12	SPACER	4 EA
ans.	MLSS100-11	LOCKING HEADER	1 EA
C1	630-09472	CAP 4700p 100V CERAMIC	1 EA
C2	630-09472	CAP 4700p 100V CERAMIC	1 EA
C3	030-38108	CAP 1µ 63V ELECT	1 EA
C4	630-09472	CAP 4700p 100V CERAMIC	1 EA
C5	630-09472	CAP 4700p 100V CERAMIC	1 EA
C6	030-38108	CAP 1µ 63V ELECT	1 EA
C7	030-36229	CAP 22µ 25V ELECT	1 EA
C8	370-11334	CAP 0.33µ 63V FILM	1 EA
C9	370-11334	CAP 0.33µ 63V FILM	1 EA
C10	030-36109	CAP 10µ 25V ELECT	1 EA
C11	370-11334	CAP 0.33µ 63V FILM	1 EA
CRl	1N4001	DIODE GEN PURP	1 EA
Ll	10A212P1	COIL 7t %"ID, #20 R-6	1 EA

4	20B1594G1	PCB ASM VSWR CONTROL R-9	1 EA
Symbol	Part No.	Description	Quantity
Q1	MPS8098	TRANSISTOR NPN AMP	1 EA
Q2	MPS8098	TRANSISTOR NPN AMP	1 EA
Q3	MPS8098	TRANSISTOR NPN AMP	I EA
Q4	MJE350	TRANSISTOR PNP SWITCHING	1 EA
RI	3R152P513J	RES ¼W 5% 51k	1 EA
R2	3R152P104J	RES 14W 5% 100k	. 1 EA
R3	3R152P101J	RES ¼W 5% 100Ω	1 EA
R4	3299W-1-104	POT 100k	1 EA
R5	2322 191 31009	RES 1.6W 5% 10Ω	1 EA
R6	PR37J 470 OHM	RES 1W 5% 470Ω	1 EA
R7	3R152P106J	RES %W 5% 10M	1 EA
R8	3R152P103J	RES ₩W 5% 10k	1 EA
R9	3R152P101J	RES ¼W 5% 100Ω	1 EA
R10	CW5-500 OHMS	RES 5W 5% 500Ω	l EA
R11	3R152P203J	RES 3W 58 20k	2 m-
R12	3R152P104J	RES 3W 5% 100k	1 EA
R13	3R152P202J	RES -4W 5% 2k	1 EA
R14	3R152P103J	RES 34W 5% 10k	1 EA
R15	3R152P473J	RES - W 58 47k	1 EA
R16	3R152P473J	RES 34W 58 47K	1 EA
R17	3R152P103J	RES 4W 5% 10k	1 EA
R18	3R152P104J	RES 34W 58 100k	1 EA
R19	3R152P202J	RES %W 5% 2k	1 EA
R20	3R152P102J	RES 4W 58 1k	1 EA 1 EA
R21	3329H-1-102	POT 1k	1 EA
R22	3R152P472J	RES 4W 5% 4.7k	1 EA
R23	3R152P472J	RES *W 5% 4.7k	1 EA
R24	3R152P392J	RES ¾W 5% 3.9k	l EA
R25	3R152P101J	RES ¼W 5% 100Ω	1 EA
R26	3R152P914J	RES ¼W 5% 910k	1 EA
R27	3R152P103J	RES >w 5% 10k	1 EA
R28	3R152P102J	RES ¼W 5% 1k	1 EA
R29	3R152P204J	RES ¼W 5% 200k	1 EA
R30	3R152P202J	RES > W 5% 2k	1 EA
U1	MC78L24CP	IC 24 VOLT REG	1 EA
U2	LM358N	IC OP AMP	1 EA
uз	LM358N	IC OP AMP	1 EA
U4	LM358N	IC OP AMP	1 EA
VR1	1N5366B	DIODE ZENER 39V	1 EA

Level	Parent No.	Description	Quantity
3	40D1493G1	1.5kw module asm ch2-4 R-9	1 EA
4	40D1472G1	PCB ASSY OUTPUT CH2-4 R-15	1 EA
Symbol	Part No.	Description	Quantity
	40D1472	PATTERN/ASM DWG	EA
	30C1306	SCHEMATIC 1 R-6	EA
	30C1307	SCHEMATIC 2	EA
	40D1472P1	PCB OUTPUT COMBINER R-4	1 EA
	1280B	TURRET TERMINAL	6 EA
	100058	FUSE CLIP	12 EA
	UT-85C TP 50	COAX CABLE 50 OHM TIN PLATED	4 FT
C5	341-29474	CAP 0.47µ 100V FILM	6 EA
_ C8	341-29474	CAP 0.47µ 100V FILM	6 EA
C9	100B-102-JP100X	CAP 1000p 100V CHIP	6 EA
C10	2222-119-28479	CAP 47µ 63V ELECT	6 EA
C11	100B-102-JP100X	CAP 1000p 100V CHIP	6 EA
C12	2222-119-28479	CAP 47µ 63V ELECT	6 EA
C13	175B-820-JP500X	CAP 82p 500V CHIP	6 EA
C14	100B-181-JP300X	CAP 180p 300V CHIP	6 EA
C15	100B-181-JP300X	CAP 180p 300V CHIP	6 EA
C16	100B-560-JP500X	CAP 56p 500V CHIP	6 EA
C102	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C104	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C105	100B-300-JP500X	CAP 30p 500V CHIP	1 EA
C109	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C110	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C111	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C114	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C115	100B-300-JP500X	CAP 30p 500V CHIP	1 EA
C119	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C120	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C121	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C124	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C125	100B-300-JP500X	CAP 30p 500V CHIP	1 EA
C127	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C130	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C131	100B-330-JP500X	CAP 33p 500V CHIP	1 EA
C132	100B-680-JP500X	CAP 68p 500V CHIP	1 EA
C133	100B-330-JP500X	CAP 33p 500V CHIP	1 EA 1 EA
C134	100B-330-JP500X	CAP 33p 500V CHIP	
C136	100B-680-JP500X	CAP 68p 500V CHIP	l EA
C137	100B-680-JP500X	CAP 68p 500V CHIP	1 EA
C141	100E-330-JP3600X	CAP 33p 3600V CHIP	1 EA
C143	200B-393-MP50X	CAP 39n 50V CHIP	1 EA
C146	200B-393-MP50X	CAP 39n 50V CHIP	1 EA

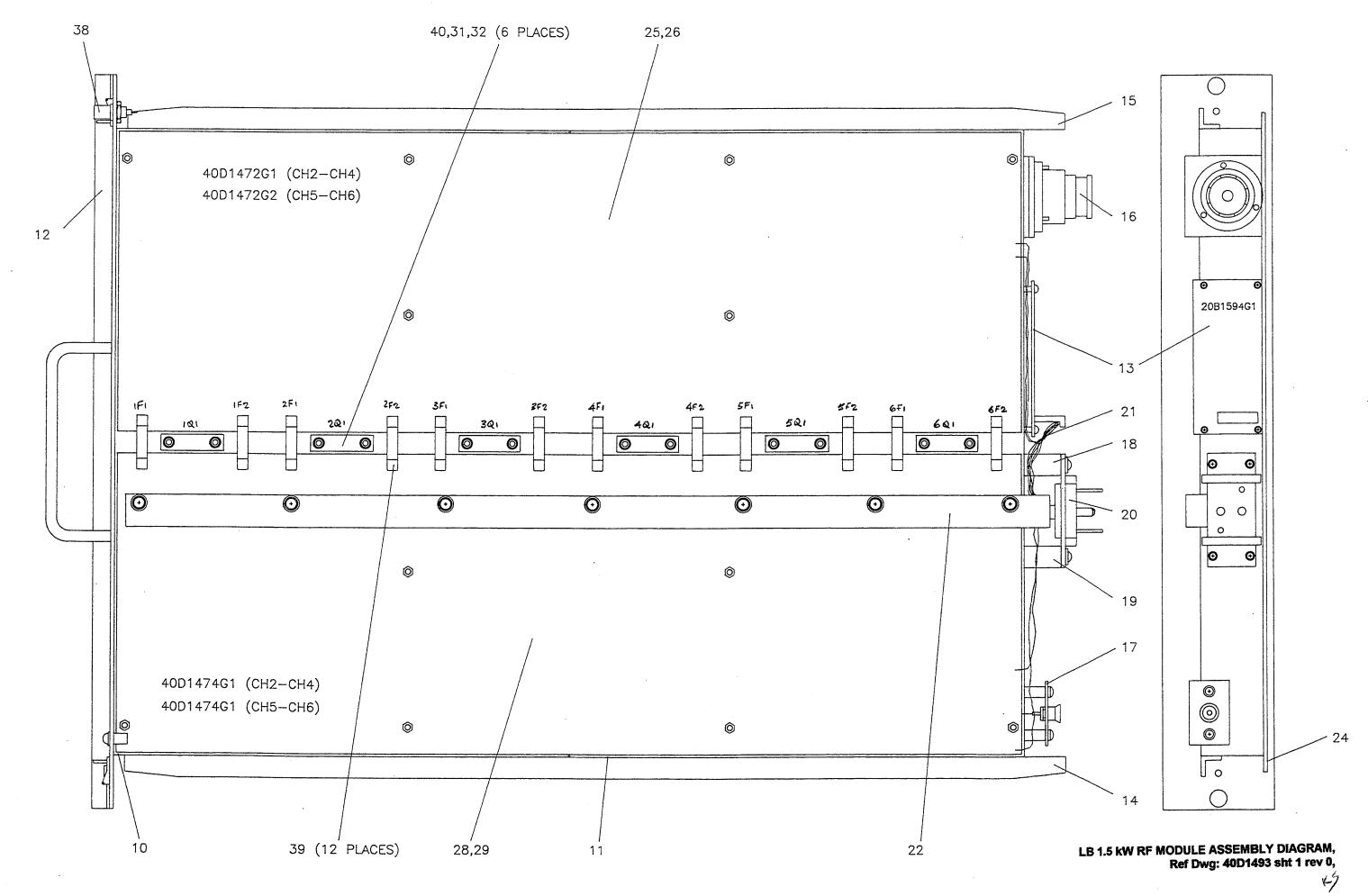
4		PCB ASSY OUTPUT CH2-4 R-15	1 EA
	Part No.		Quantity
CR100	HP5082-2800	DIODE see ECG#503 or lN5711	1 EA
CR101	HP5082-2800		1 EA
L4	1-7/32-5-CW-20	COIL 20B1627 5t 20AWG 7/32 ID	6 EA
L5	1-7/32-5-CW-20	COIL 20B1627 5t 20AWG 7/32 ID	6 EA
L106	5-3/16-11-CW-20	COIL 20B1627 11t 20AWG 3/16 ID	1 EA
L107	5-3/16-11-CW-20	COIL 20B1627 11t 20AWG 3/16 ID	1 EA
L108	5-3/16-11-CW-20	COIL 20B1627 11t 20AWG 3/16 ID	1 EA
R100		RES 250W 5% 100Ω	1 EA
R102	PPR9752503100-5	RES 250W 5% 100Ω	1 EA
R104	PPR9752503100-5	RES 250W 5% 100Ω	1 EA
R106	PPR9752503 50-5	RES 250W 5% 50Ω	1 EA
R107	PPR9752503 50-5	RES 250W 5% 50Ω	1 EA
Rl08	PPR9752503 50-5		1 EA
R112	9C12063A1100JL	RES ¾W 5% 110Ω CHIP	1 EA
R113	PR37J 47 OHMS	RES 1.6W 5% 47Ω	1 EA
R114	PR37J 51 OHMS	RES 1.6W 5% 51Ω	1 EA
R115	PR37J 47 OHMS	RES 1.6W 5% 47Ω	1 EA
R116	9C12063A1100JL	RES ₩W 5% 110Ω CHIP	1 EA
		LARCAN INC. Parts List	
Level	Parent No.	Description	Quantity
3	40D1493G1	1.5kw module asm ch2-4 R-9	I EA
4	40D1474G1	PCB ASM INPUT CH2-4 R-14	1 EA
Symbol	Part No.	Description	Quantity
	40D1474	ASSEMBLY DRAWING R-3.4	EA
	30C1306	SCHEMATIC 1 R-6	EA
	30C1307	SCHEMATIC 2	EA
	40D1474P1	PCB INPUT SPLITTER R-3	1 EA
	B1537-B-1/8-12	SPACER	7 EA
	100058	FUSE CLIP	12 EA
	2865000 202	BALUN CORE for T1	6 EA
C1	100B-201-JP300X	CAP 200p 300V CHIP	6 EA
C2	100B-201-JP300X	CAP 200p 300V CHIP	6 EA
C3	100B-620-JP500X	CAP 62p 500V CHIP	6 EA
C4	100B-201-JP300X	CAP 200p 300V CHIP	6 EA
C6			
c 7	200B-393-MP50X	CAP 39n 50V CHIP	6 EA

4	40D1474G1	PCB ASM INPUT CH2-4 R-14	1 EA
Symbol	Part No.	Description	Quantity
C101	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C103	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C106	100B-270-JP500X	CAP 27p 500V CHIP	1 EA
C107	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C108	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C112	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C113	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C116	100B-270-JP500X	CAP 27p 500V CHIP	1 EA
C117	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C118	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C122	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C123	100B-150-JP500X	CAP 15p 500V CHIP	1 EA
C126	100B-270-JP500X	CAP 27p 500V CHIP	1 EA
C128	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C129	100B-121-JP300X	CAP 120p 300V CHIP	1 EA
C135	100B-330-JP500X	CAP 33p 500V CHIP	1 EA
C138	100B-680-JP500X	CAP 68p 500V CHIP	1 EA
C139	100B-330-JP500X	CAP 33p 500V CHIP	1 EA
C140	100B-330-JP500X	CAP 33p 500V CHIP	1 EA
C142	100B-680-JP500X	CAP 68p 500V CHIP	1 EA
C144	100B-680-JP500X	CAP 68p 500V CHIP	1 EA
C145	100B-330-JP500X	CAP 33p 500V CHIP	1 EA
C147	200B-393-MP50X	CAP 39n 50V CHIP	l EA
C148	100B-3R3-CP500X	CAP 3.3p 500V CHIP	1 EA
C149	200B-393-MP50X	CAP 39n 50V CHIP	1 EA
C150	100B-102-JP100X	CAP 1000p 100V CHIP	1 EA
CR102	HP5082-2800	DIODE see ECG#503 or 1N5711	1 EA
L109	5-3/16-11-CW-20	COIL 20B1627 11t 3/16 ID #20AWG	1 EA
L110	5-3/16-11-CW-20	COIL 20B1627 11t 3/16 ID #20AWG	1 EA
L111	5-3/16-11-CW-20	COIL 20B1627 11t 3/16 ID #20AWG	1 EA
R1	9C12063A2702JL	RES 14W 5% 27k CHIP	1 EA
R2	3269W-001-104	POT 100k	6 EA
R3	SRF25HM5R1J	RES ¼W 5% 5.1Ω sub 3R77P5R1J	6 EA
R4	3R152P472J	RES ₩ 5% 4.7k	6 EA
R5	3R152P472J	RES ¼W 5% 4.7k	6 EA
R6	SRF25HM5R1J	RES ₩ 5% 5.1Ω sub 3R77P5R1J	6 EA
R7	3269W-001-104	POT 100k	6 EA
R8	9C12063A2702JL	RES WW 5% 27k CHIP	6 EA
R9	9C12063A1502JL	RES ₩ 5% 15k CHIP	6 EA 6 EA
R10	9C12063A1502JL	RES ¼W 5% 15k CHIP	ALE O
R101	PPR515203 100-5	RES 20W 5% 100Ω	1 EA
R103	PPR515203 100-5	RES 20W 5% 100Ω	1 EA
R105	PPR515203 100-5	RES 20W 5% 100Ω	1 EA
R109	PPR515203 50-5	RES 20W 5% 50Ω	1 EA
R110	PPR515203 50-5	RES 20W 5% 50Ω	1 EA
R111	PPR515203 50-5	RES 20W 5% 50Ω	1 EA
R117	9C12063A1100JL	RES ¼W 5% 110Ω CHIP	1 EA
R118	9C12063A1100JL	RES ¾W 5% 110Ω CHIP	1 EA

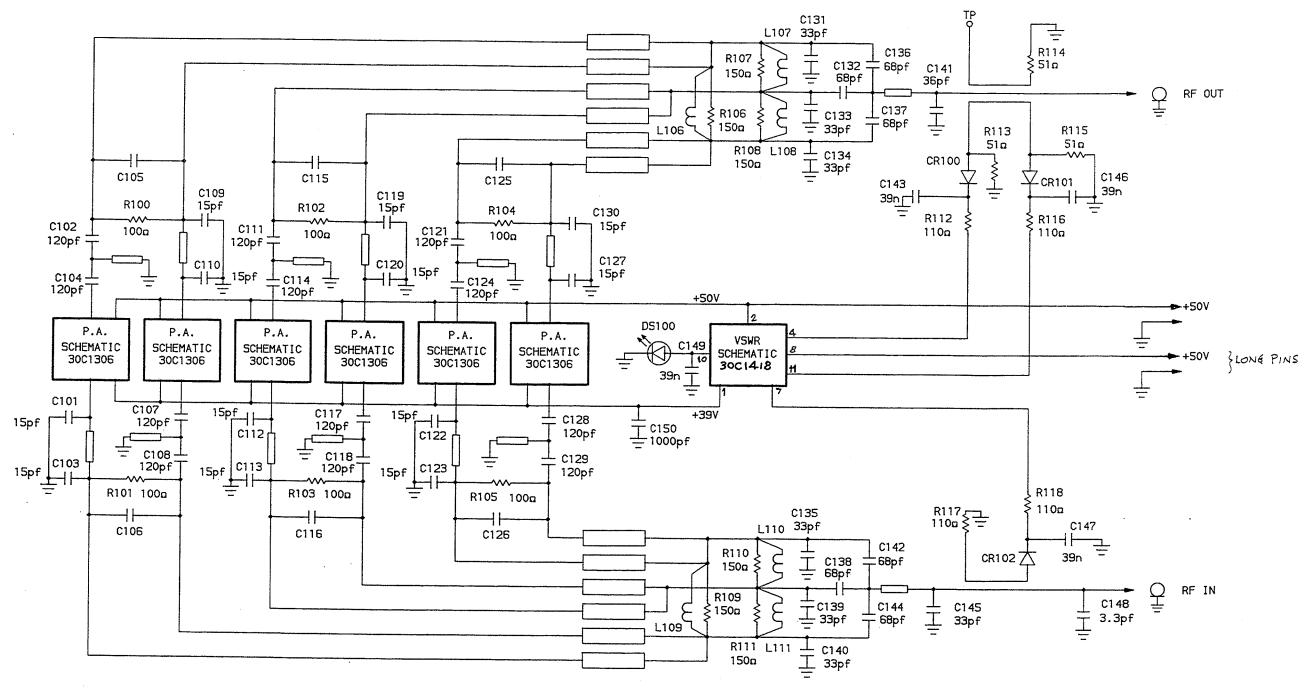
4	. 40D1474G1	PCB ASM INPUT CH2-4 R-14	1 EA
Symbol	Part No.	Description	Quantity
RT1 RT2	MSC154K MSC154K	THERMISTOR THERMISTOR	6 EA 6 EA
Tl	10A1434	BALUN 5" RG-178/U	6 EA

^{**} END OF CH 2-4" PARTS LIST **

Notes:

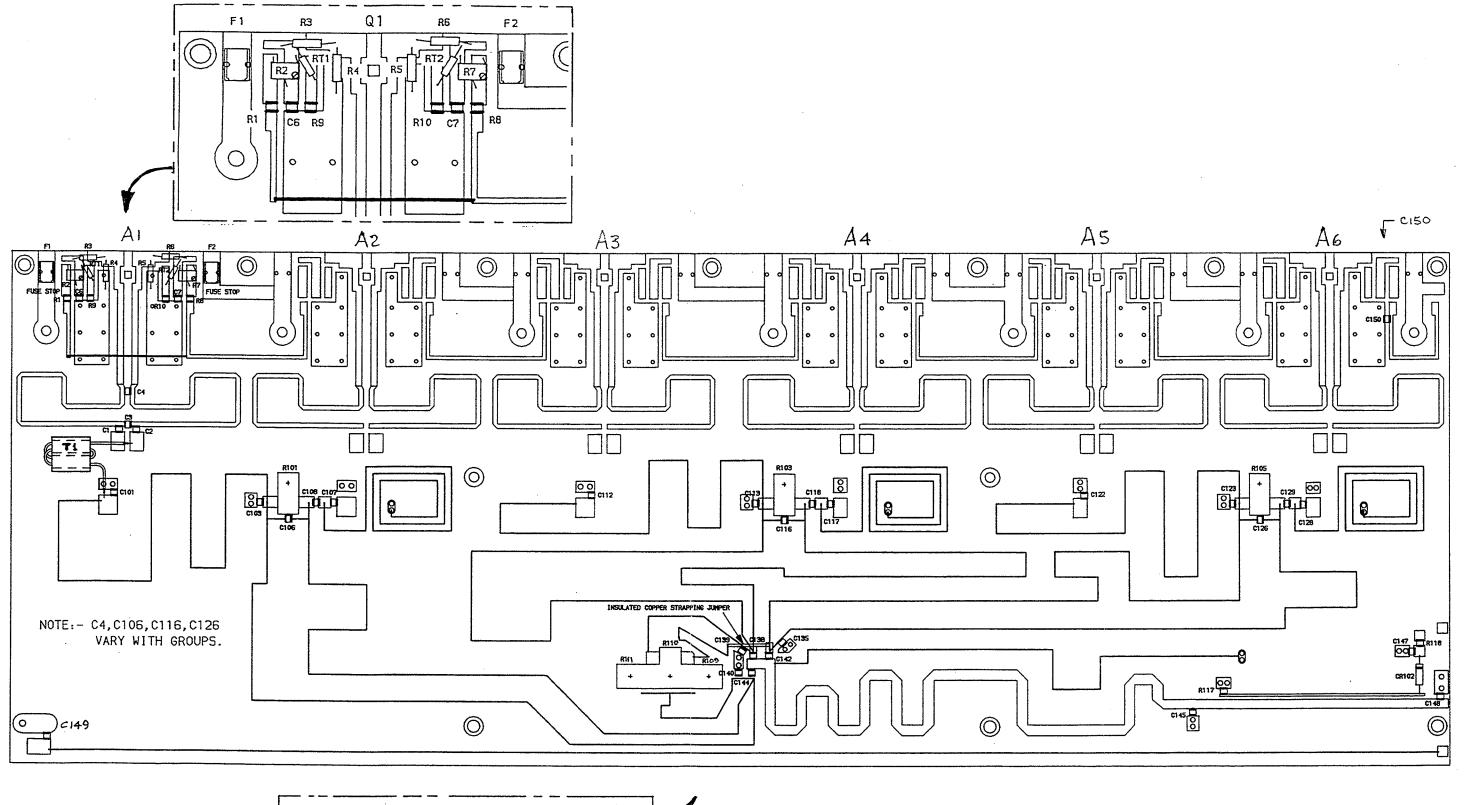


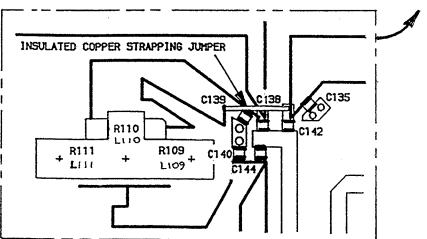
PUB96-28 rev 1: Figure 28-3.



C#	CH. 2-4	CH. 5-6
C105	33pf	22pf
C106	33pf	22pf
C115	33pf	22pf
C116	33pf	22pf
C125	33pf	22pf
C126	33pf	22pf

LB 1.5 kW RF MODULE WIRING DIAGRAM, Ref Dwg: 30C1307 sht 1 rev 2,

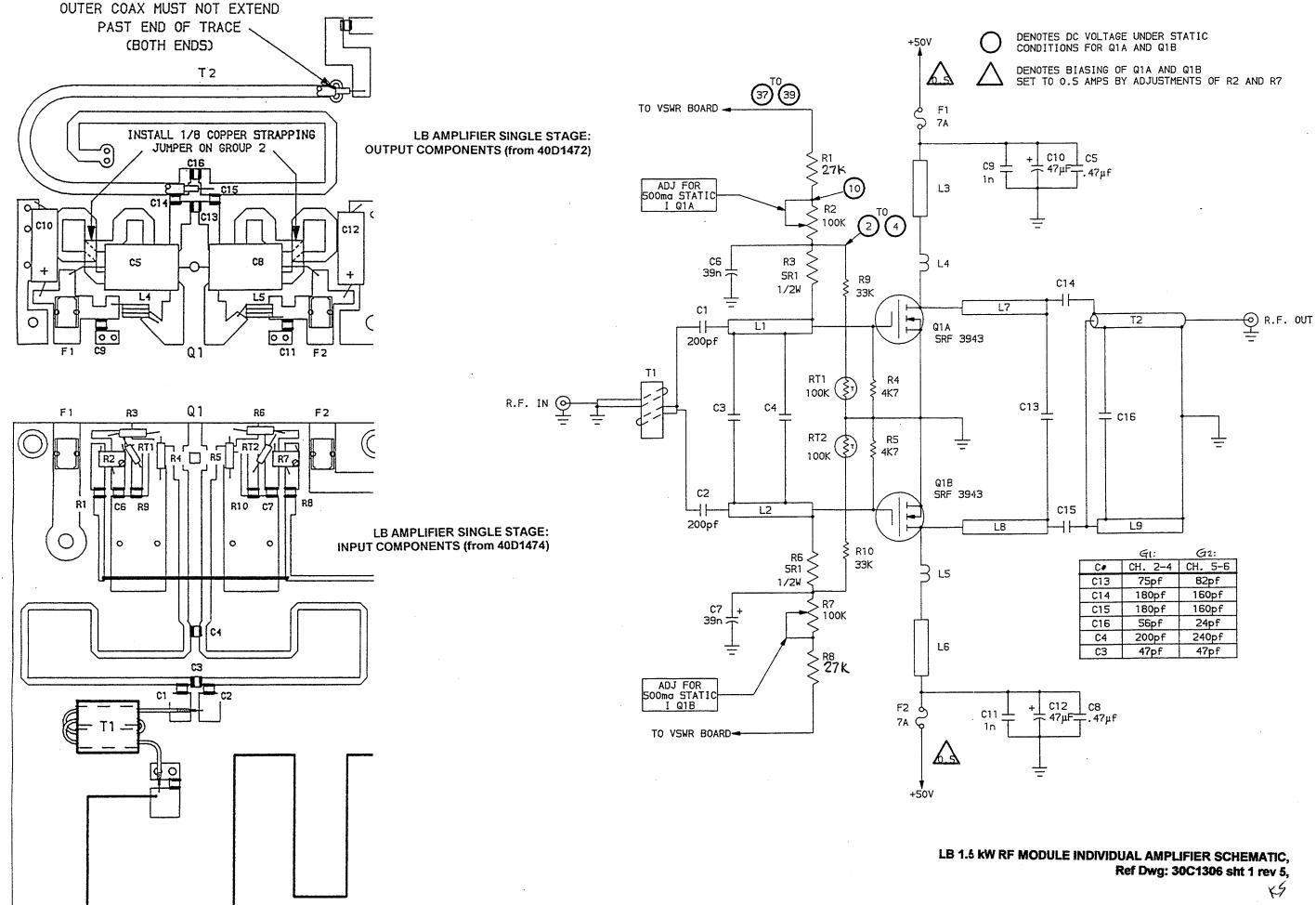




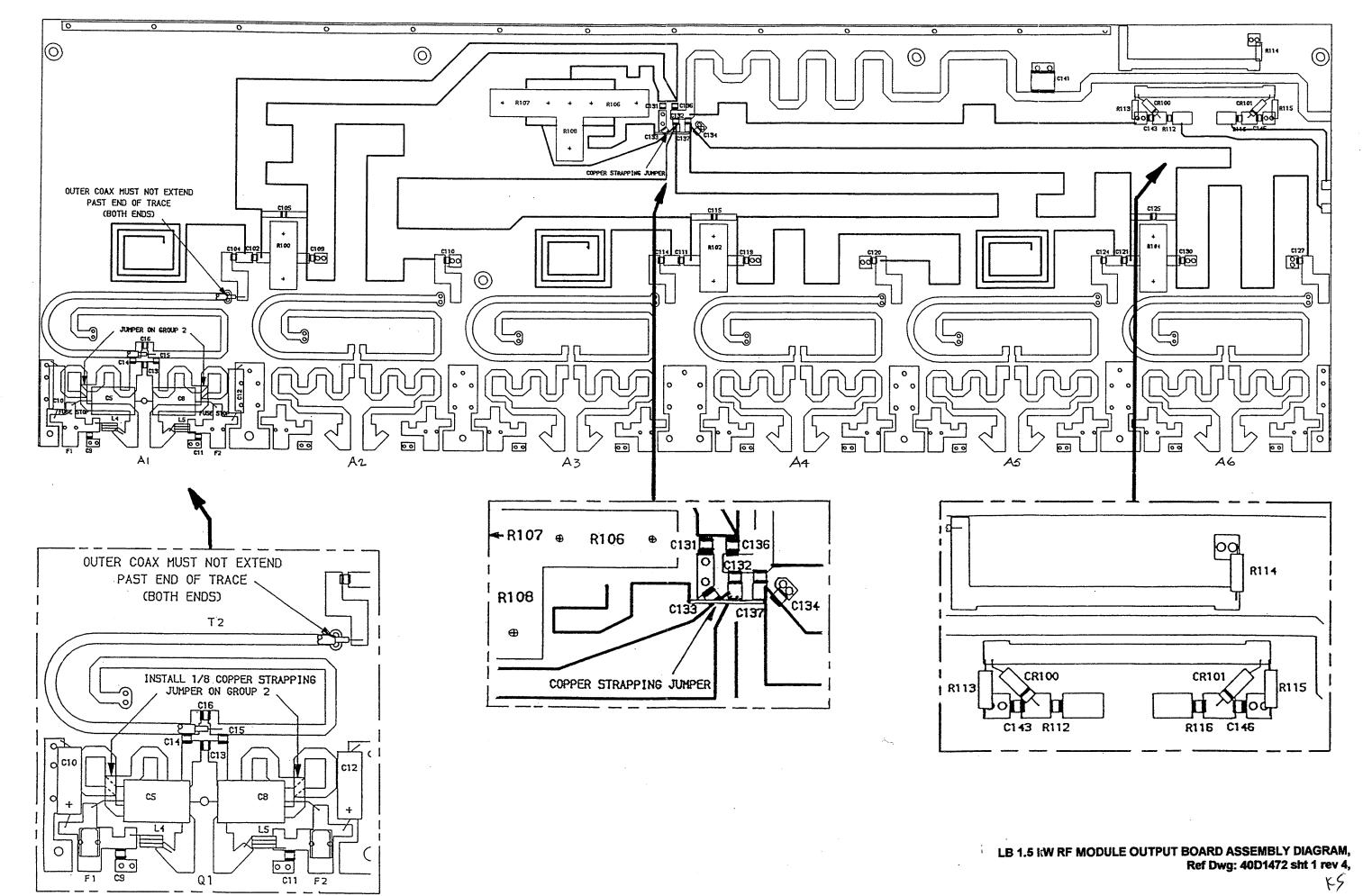
LB 1.5 kW RF MODULE INPUT BOARD ASSEMBLY DIAGRAM, Ref Dwg: 40D1474 sht 1 rev 3.2,

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PUB96-28 rev 1: Figure 28-5.

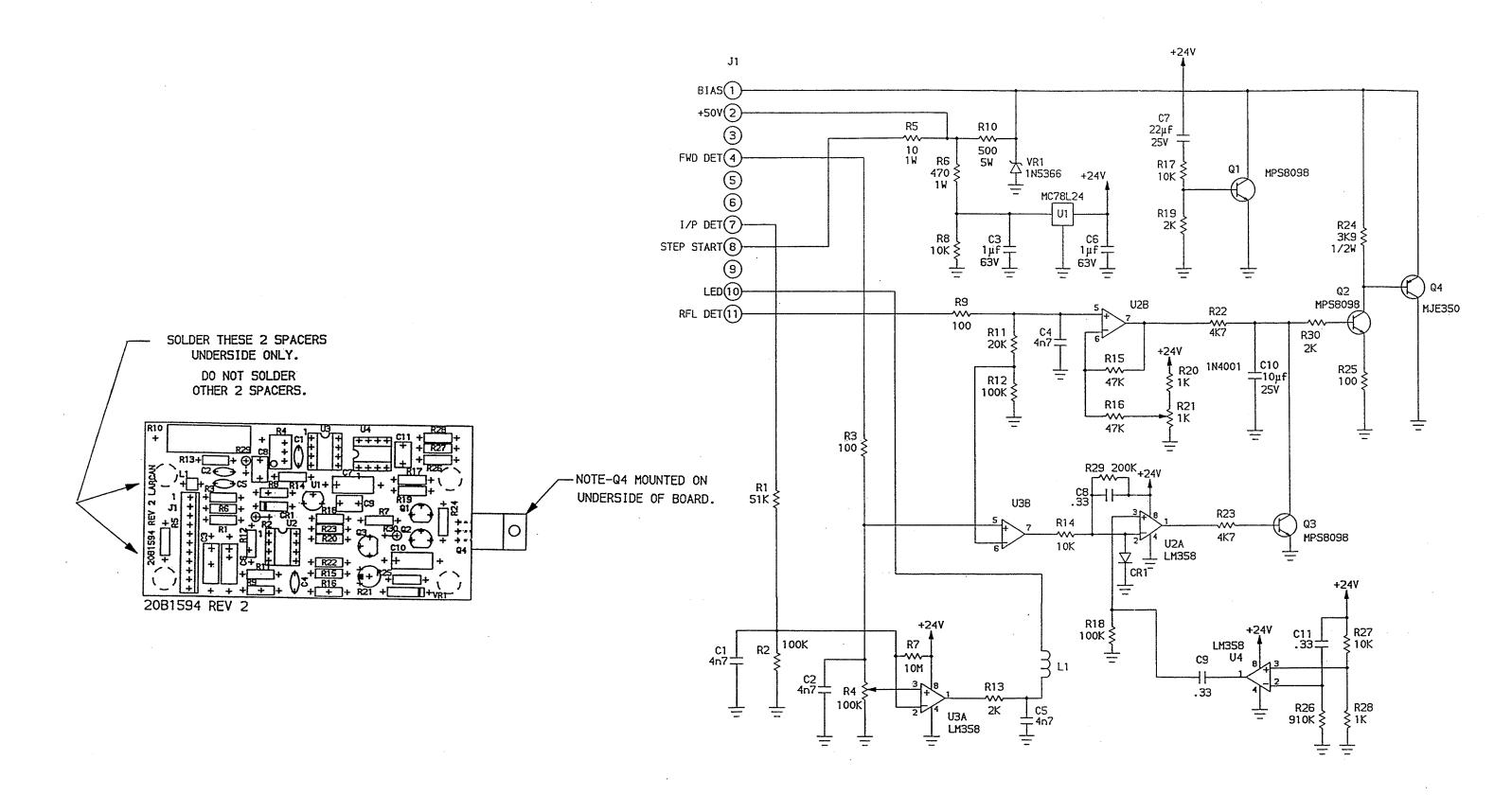


PUB96-28 rev 1: Figure 28-6.



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PUB96-28 rev 1: Figure 28-7.



RF MODULE OUTPUT VSWR CONTROL BOARD: Assembly Ref Dwg: 20B1594 sht 1 rev 2, Schematic Ref Dwg: 30C1418 sht 1 rev 6,